- Alievalent incorporation -Aliw pritza-cetri si loiseatem teen / true-co9 a confermite no la posticular et a posticular expression en contact with X2 gas. $m^{2+} \chi^{2-} (\chi \rightarrow exygen)$ (activity) (positial pressione) was controlled over several orders of magnitude Resistance ~ conductivity TNTZ/RIUN(T,P) is orders of magnitude Possible defects: [v;], [m;], [h], [vm], [x;], le [v,']+[m;]+[h'] = [vm]+[x;]+[e'] Electroneutrality condition reaction is reverse of incorporation

 $K_{X_1} = [X_1^2][h^2]$ and $K_B = [Le'][h^2]$ [b][xi] = Kx, Px Browns approximation-T,P: only 1 +ve defect and 1 -ve defect one The majority [x] + [x] + [x] = [x] + [x] + [x]Assumed majority [Browwer Iregime] -> we have 9 in this case 80 [h] = Kx, Px, souls strict big est grighet) ln[h] + In Pxa) does not [Vx:] = [Vm] (schattky) Cases: p depend on [Vx'] = [Xi] (Anion Forenkel) lancetonal relations [vx] = [e] Brouwer segimes -> N, I and P For high postial phassure of X2 Coxidising atmosphore)

$$[h^{*}][e'] = K_{B}$$

$$\Rightarrow [e'] = K_{B}$$

$$\text{Since [h^{*}]} \propto P_{X_{2}}^{V_{M}} \Rightarrow [e'] \propto P_{X_{2}}^{V_{M}}$$

$$\text{If [h^{*}]} \text{ in I sugaism whose canism - Foundard is active. So}$$

$$[X_{1}^{*}] = [V_{X}^{*}]$$

$$[X_{1}^{*}] = [V_{X}^{*}]$$

$$\text{Exi} = [K_{AF}]$$

$$\text{Now [h^{*}]}[X_{1}^{*}] = K_{AF}$$

$$\text{Now [h^{*}]}[X_{1}^{*}] = K_{AF}$$

$$\text{Pred}$$

$$\text{So [h^{*}]} \propto P_{X_{2}}^{V_{2}}$$

$$\text{In [h^{*}]} \xrightarrow{(-V_{R})} \text{(VM)}$$

$$\text{In [h^{*}]} \xrightarrow{$$